

Product data sheet

1. Product profile

1.1 General description

Two planar PIN diodes in series configuration in a SOT323 small SMD plastic package.

1.2 Features

- High voltage current control RF resistor for RF attenuators
- Low diode capacitance
- Low series inductance

1.3 Applications

RF attenuators and switches

2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Symbol
1	anode		_
2	cathode	3	3
3	common connection	1 2 sot323_so	2 sym015

3. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BAP70-04W	-	plastic surface-mounted package; 3 leads	SOT323



4. Marking

Table 3. Marking codes

Type number	Marking code
BAP70-04W	1Np

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		, ,	,		
Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_R	continuous reverse voltage		-	50	V
I _F	continuous forward current		-	100	mA
P _{tot}	total power dissipation	T _s = 90 °C	-	260	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-s)}$	thermal resistance from junction to soldering point		230	K/W

7. Characteristics

Table 6. Characteristics

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	•					
V _F	forward voltage	I _F = 50 mA	-	0.95	1.1	V
I _R	reverse current	V _R = 50 V	-	-	100	nΑ
C _d	diode capacitance	see Figure 1; f = 1 MHz				
		$V_R = 0 V$	-	600	-	fF
		$V_R = 1 V$	-	430	-	fF
		$V_R = 20 \text{ V}$	-	250	300	fF
	diode forward resistance	see Figure 2; f = 100 MHz				
		$I_F = 0.5 \text{ mA}$	-	77	100	Ω
		$I_F = 1 \text{ mA}$	-	40	50	Ω
		I _F = 10 mA	-	5.4	7	Ω
		$I_F = 100 \text{ mA}$	-	1.4	1.9	Ω
τ∟	charge carrier life time	when switched from I $_{F}$ = 10 mA to I $_{R}$ = 6 mA; R_{L} = 100 $\Omega;$ measured at I $_{R}$ = 3 mA	-	1.25	-	μs
L _S	series inductance	$I_F = 100 \text{ mA}; f = 100 \text{ MHz}$	-	1.4	-	nΗ
BAP70-04W_2				© N	IXP B.V. 2007. AI	I rights reserv

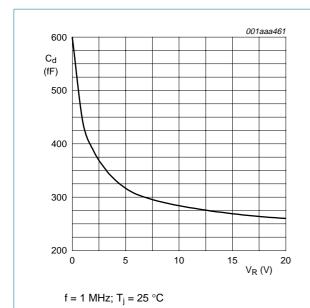


Fig 1. Diode capacitance as a function of reverse voltage; typical values

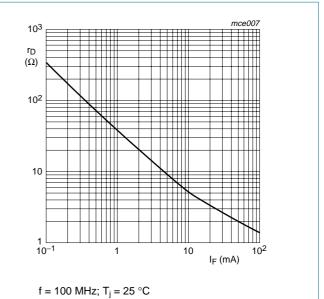


Fig 2. Forward resistance as a function of forward current; typical values

8. Package outline

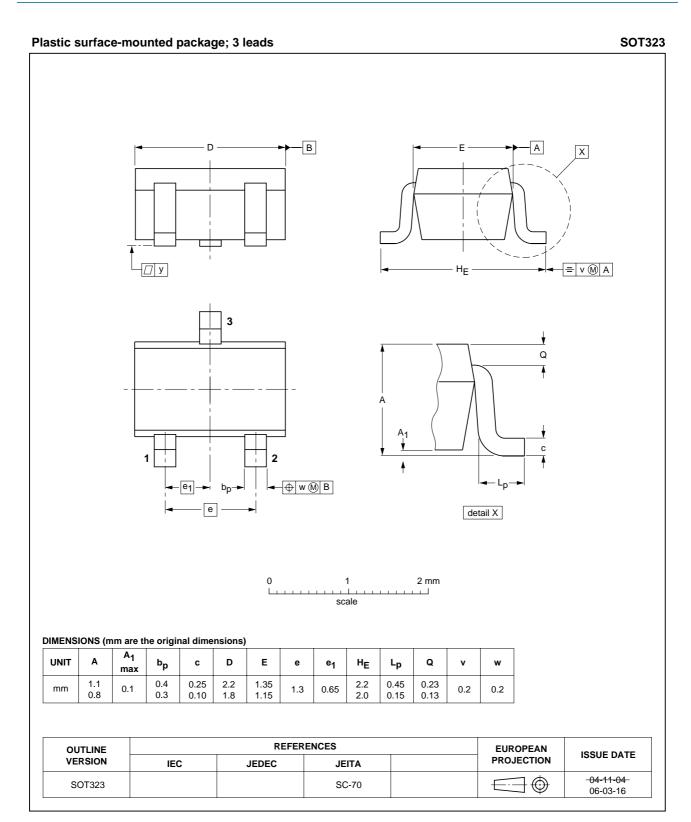


Fig 3. Package outline SOT323

BAP70-04W

Silicon PIN diode

9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP70-04W_2	20070403	Product data sheet	-	BAP70-04W_1
Modifications:	guidelines o Legal texts I	of this data sheet has been if NXP Semiconductors. have been adapted to the nanged max value of reverse	ew company name whe	re appropriate.
BAP70-04W_1 (9397 750 12557)	20040305	Product data	-	

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

10.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

10.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

10.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

11. Contact information

For additional information, please visit: http://www.nxp.com

For sales office addresses, send an email to: salesaddresses@nxp.com

BAP70-04W_2 © NXP B.V. 2007. All rights reserved.

12. Contents

1	Product profile
1.1	General description 1
1.2	Features
1.3	Applications
2	Pinning information 1
3	Ordering information
4	Marking 2
5	Limiting values
6	Thermal characteristics 2
7	Characteristics
8	Package outline 4
9	Revision history 5
10	Legal information 6
10.1	Data sheet status 6
10.2	Definitions
10.3	Disclaimers 6
10.4	Trademarks6
11	Contact information 6
12	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

